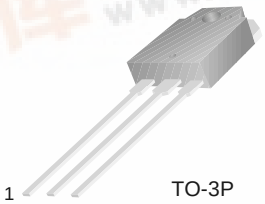
FAIRCHILD SEMICONDUCTOR™

KSC2751

High Speed
High Current Switching Industrial Use



TO-3P

1.Base 2.Collector 3.Emitter

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	500	V
V_{CEO}	Collector-Emitter Voltage	400	V
V_{EBO}	Emitter-Base Voltage	7	V
I_C	Collector Current (DC)	15	A
I_{CP}	*Collector Current (Pulse)	30	A
I_B	Base Current (DC)	7.5	A
P_C	Collector Dissipation (T_C=25°C)	120	W
T_J	Junction Temperature	150	°C
T_{STG}	Storage Temperature	- 55 ~ 150	°C

* PW≤300μs, Duty Cycle≤10%

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min	Typ	Max	Units
V_{CEO} (sus)	Collector-Emitter Sustaining Voltage	I_C = 10A, I_{B1}= 2A, L = 50μH	400			V
V_{CEX}(sus)1	Collector-Emitter Sustaining Voltage	I_C = 10A, I_{B1}= -I_{B2} = 2A T_C =125°C, I = 180μH, Clamped	450			V
V_{CEX}(sus)2	Collector-Emitter Sustaining Voltage	I_C = 20A, I_{B1} = 4A, -I_{B2} = 2A T_C= 125°C, L = 180μH,Clamped	400			V
I_{CBO}	Collector Cut-off Current	V_{CB} = 400V, I_E = 0			100	μA
I_{CER}	Collector Cut-off Current	V_{CE} = 400V, R_{BE} = 50Ω @ T_C = 125°C			2	mA
I_{CEX1}	Collector Cut-off Curren	V_{CE} = 400V, V_{BE}(off) = -1.5V			100	μA
I_{CEX2}	Collector Cut-off Current	V_{CE} = 400V, V_{BE}(off) = -1.5V @ T_C = 125Ω			1	mA
I_{EBO}	Emitter Cut-off Current	V_{EB} = 5V, I_C = 0			10	μA
h_{FE1} h_{FE2} h_{FE3}	* DC Current Gain	V_{CE} = 5V, I_C = 2A V_{CE} = 5V, I_C = 5A V_{CE} = 5V, I_C = 10A	15 10 7	35	80	
V_{CE}(sat)	* Collector-Emitter Saturation Voltage	I_C = 10A, I_B = 2A		0.3	1	V
V_{BE}(sat)	* Base Emitter ON Voltage	I_C = 10A, I_B = 2A		1	1.5	V
t_{ON}	Turn ON Time	V_{CC} = 150V, I_C = 10A I_{B1} = -I_{B2} = 2A R_L = 15Ω			1	μs
t_{STG}	Storage Time				2.5	μs
t_F	Fall Time				0.7	μs

* Pulse Test: PW≤350μs, Duty Cycle≤2% Pulsed

h_{FE} Classificntion

Classification	N	R	O	Y
h_{FE1}	15 ~ 30	20 ~ 40	30 ~ 60	40 ~ 80

Typical Characteristics

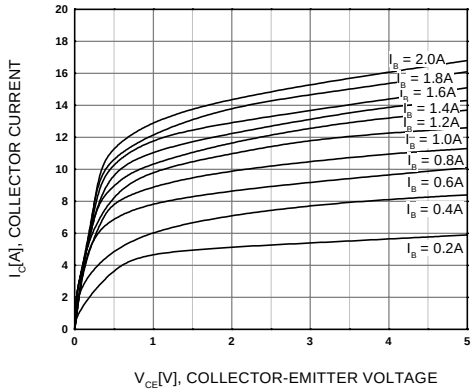


Figure 1. Static Characteristic

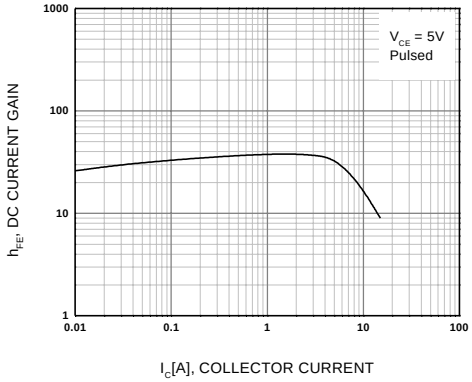


Figure 2. DC current Gain

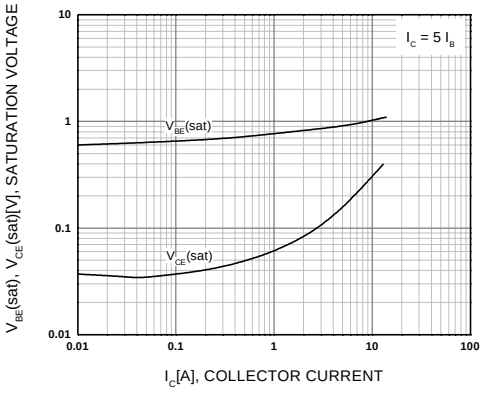


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

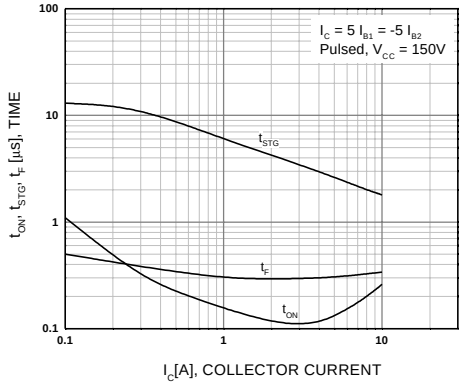


Figure 4. Switching Time

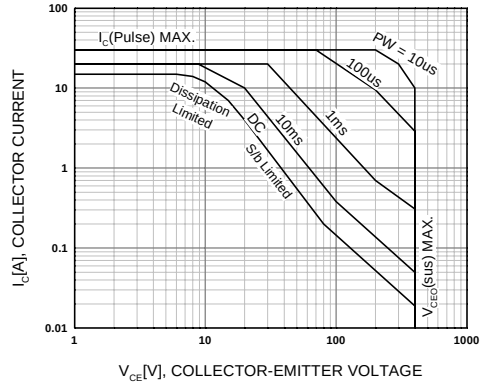


Figure 5. Safe Operating Area

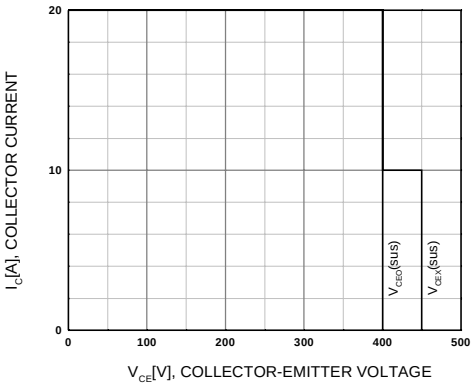


Figure 6. Reverse Bias Safe Operating Area

Typical Characteristics (Continued)

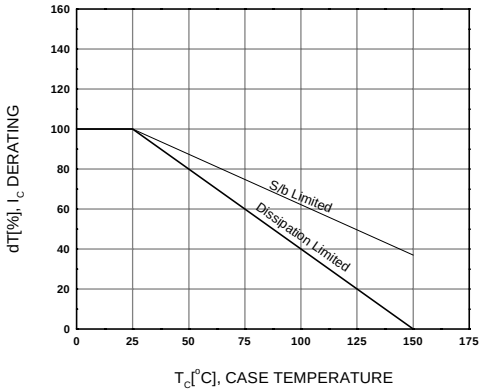


Figure 7. Derating Curve of Safe Operating Area

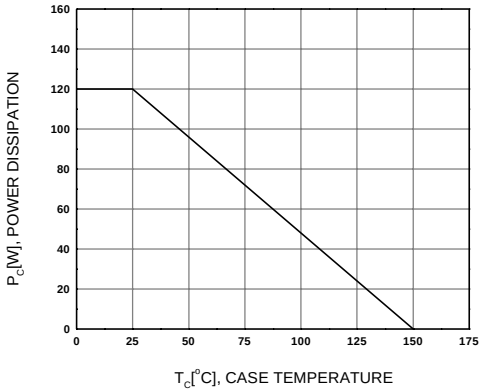
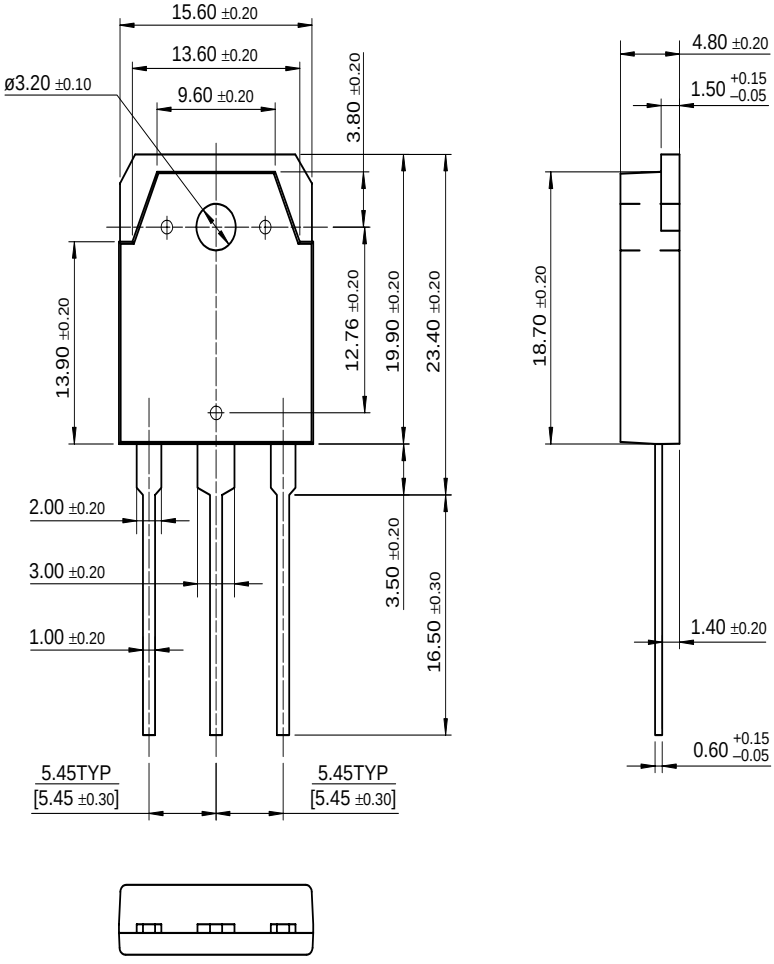


Figure 8. Power Derating

Package Demensions

TO-3P



Dimensions in Millimeters

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